

70T659S12BFI

70T659S12BFI Information

n heisenter	70T659S12BFI IDT, Integrated Device Technology Inc Integrated Circuits (ICs) Memory IC SRAM 4.5MBIT 12NS 208CABGA 208-LFBGA For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



70T659S12BFI Specifications

	Report errors?
Supplier Device Package	208-CABGA (15x15)
Package / Case	208-LFBGA
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Voltage - Supply	2.4 V ~ 2.6 V
Access Time	12ns
Write Cycle Time - Word, Page	12ns
Clock Frequency	-
Memory Interface	Parallel
Memory Size	4.5Mb (128K x 36)
Technology	SRAM - Dual Port, Asynchronous
Memory Format	SRAM
Memory Type	Volatile
Series	-
Package	208-LFBGA
	Memory
Category	Integrated Circuits (ICs)
Manufacturer	IDT, Integrated Device Technology Inc
Manufacturer Part Number	70T659S12BFI

70T659S12BFI Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE UARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

70T659S12BFI Payment Methods





If you have any question about 70T659S12BFI, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com